

## PATENT ASSIGNMENT COVER SHEET

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Stylesheet Version v1.2

EPAS ID: PAT4193287

<b>SUBMISSION TYPE:</b>	NEW ASSIGNMENT
<b>NATURE OF CONVEYANCE:</b>	ASSIGNMENT
<b>CONVEYING PARTY DATA</b>	
<b>Name</b>	<b>Execution Date</b>
ANUP BHALLA	07/25/2012
HAMZA YILMAZ	07/26/2012
MADHUR BOBDE	07/25/2012
LINGPENG GUAN	07/27/2012
JUN HU	07/25/2012
JONGO H KIM	07/25/2012
YONGPING DING	07/25/2012
<b>RECEIVING PARTY DATA</b>	
<b>Name:</b>	ALPHA AND OMEGA SEMICONDUCTOR INCORPORATED
<b>Street Address:</b>	475 OAKMEAD PARKWAY
<b>City:</b>	SUNNYVALE
<b>State/Country:</b>	CALIFORNIA
<b>Postal Code:</b>	94085
<b>PROPERTY NUMBERS Total: 1</b>	
<b>Property Type</b>	<b>Number</b>
Application Number:	15236263
<b>CORRESPONDENCE DATA</b>	
<b>Fax Number:</b>	(510)668-0239
<i>Correspondence will be sent to the e-mail address first; if that is unsuccessful, it will be sent using a fax number, if provided; if that is unsuccessful, it will be sent via US Mail.</i>	
<b>Phone:</b>	510-668-0965
<b>Email:</b>	jessica@jdipatent.com
<b>Correspondent Name:</b>	JOSHUA D. ISENBERG
<b>Address Line 1:</b>	809 CORPORATE WAY
<b>Address Line 4:</b>	FREMONT, CALIFORNIA 94539
<b>ATTORNEY DOCKET NUMBER:</b>	ANO-056/DIV/CON2
<b>NAME OF SUBMITTER:</b>	JOSHUA D. ISENBERG
<b>SIGNATURE:</b>	/Joshua D. Isenberg, Reg. No. 41088/
<b>DATE SIGNED:</b>	12/20/2016

**Total Attachments: 7**

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ASSIGNMENT

**INVENTOR AND CITY** Whereas, I, ANUP BHALLA of 1406 Block Drive Santa Clara, CA 95050, USA

have invented:

**TITLE:** HIGH VOLTAGE FIELD BALANCE METAL OXIDE FIELD EFFECT TRANSISTOR (FBM)

**DATE INVENTOR SIGNED THE DECLARATION** and executed a United States patent application therefor on July 25<sup>th</sup>, 2012. Said assignor hereby authorize and request their attorney, Joshua D. Isenberg, of 809 Corporate Way, Fremont, California, to insert here in parentheses (Application number 15/236,263, filed August 12, 2016) the filing date and application number of said application when known.

Whereas, Alpha and Omega Semiconductor Incorporated, a California Corporation, having its registered address at 475 Oakmead Pkwy, Sunnyvale, CA 94085, (hereinafter called AOS), desires to acquire the entire right, title and interest of said application and invention, and to any United States and foreign patents to be obtained therefore;

Now therefore for a valuable consideration, receipt whereof is hereby acknowledged, I, the above named, hereby sell, assign, and transfer to AOS, its successors and assigns, the entire right, title and interest in the said application and invention therein disclosed for the United States and foreign countries, and all rights of priority resulting from the filing said United States application, and I request the Commissioner of Patents to issue any Letters Patent granted upon the invention set forth in said application to AOS its successors and assigns; and I hereby agree that AOS may apply for foreign Letters Patent on said invention and I will execute all papers necessary in connection with the United States and foreign applications when called upon to do so by

**CITY AND** Signed and Sealed at Sunnyvale, CA

**DATE** on July 25<sup>th</sup>, 2012

Anup Bhalla  
Anup Bhalla

ASSIGNMENT

**INVENTOR AND CITY** Whereas, I, **HAMZA YILMAZ** of **20755 Trinity Avenue Saratoga, CA 95070, USA**

have invented:

**TITLE:** **HIGH VOLTAGE FIELD BALANCE METAL OXIDE FIELD EFFECT TRANSISTOR (FBM)**

**DATE INVENTOR SIGNED THE DECLARATION** and executed a United States patent application therefor on 7/26, 2012.


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**CITY AND** Signed and Sealed at Sunnyvale, CA

**DATE** on 7/26, 2012

  
Hamza Yilmaz

**ASSIGNMENT**

**INVENTOR AND CITY** Whereas, I, **MADHUR BOBDE** of **1602 Goldfinch Way Sunnyvale CA 94087, USA**

have invented:

**TITLE:** **HIGH VOLTAGE FIELD BALANCE METAL OXIDE FIELD EFFECT TRANSISTOR (FBM)**

**DATE INVENTOR SIGNED THE DECLARATION** and executed a United States patent application therefor on July 25<sup>th</sup>, 2012.

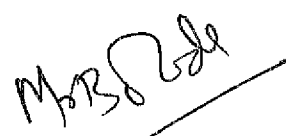
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**CITY AND** Signed and Sealed at Sunnyvale CA

**DATE** on July 25<sup>th</sup>, 2012



\_\_\_\_\_  
Madhur Bobde

ASSIGNMENT

**INVENTOR AND CITY** Whereas, I, **LINGPENG GUAN** of **1428 Shaffer Drive San Jose, CA 95132, USA**

have invented:

**TITLE:** **HIGH VOLTAGE FIELD BALANCE METAL OXIDE FIELD EFFECT TRANSISTOR (FBM)**

**DATE INVENTOR SIGNED THE DECLARATION** and executed a United States patent application therefor on 07/27, 2012.

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**CITY AND** Signed and Sealed at Sunnyvale, CA

**DATE** on 07/27, 2012

Lingpeng Guan  
Lingpeng Guan

**ASSIGNMENT**

**INVENTOR AND CITY**                   Whereas, I, **JUN HU** of **781 Acacia Avenue San Bruno, CA 94066, USA**

have invented:

**TITLE:**                           **HIGH VOLTAGE FIELD BALANCE METAL OXIDE FIELD EFFECT TRANSISTOR (FBM)**

**DATE INVENTOR SIGNED THE DECLARATION** and executed a United States patent application therefor on 07/25, 2012.

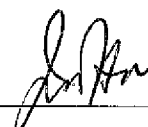
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**CITY AND**                           Signed and Sealed at Sunnyvale, CA

**DATE**                           on 7/25, 2012

  
\_\_\_\_\_  
**Jun Hu**

ASSIGNMENT

INVENTOR AND CITY Whereas, I, JONGOH KIM of 5337, NW Paseo Ter.  
Portland, Oregon 97229, USA

have invented:

TITLE: HIGH VOLTAGE FIELD BALANCE METAL OXIDE FIELD  
EFFECT TRANSISTOR (FBM)

DATE INVENTOR SIGNED THE DECLARATION and executed a United States patent application therefor

on July 25<sup>th</sup>, 2012. Said assignor hereby authorize and request their attorney, Joshua D. Isenberg, of 809 Corporate Way, Fremont, California, to insert here in parentheses (Application number 15/236,263, filed August 12, 2016) the filing date and application number of said application when known.

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CITY AND Signed and Sealed at Sunnyvale, CA

DATE on July/25th, 2012

*Jongoh Kim*

Jongoh Kim



ASSIGNMENT

INVENTOR AND CITY Whereas, I, YONGPING DING of 1246 San Moritz Dr. San Jose, CA 95132, USA

have invented:

TITLE: HIGH VOLTAGE FIELD BALANCE METAL OXIDE FIELD EFFECT TRANSISTOR (FBM)

DATE INVENTOR SIGNED THE DECLARATION and executed a United States patent application therefor on 7/25, 2012.

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CITY AND Signed and Sealed at Sunnyvale, CA

DATE on 7/25, 2012

Handwritten signature of Yongping Ding